

Physics and chemistry of nanostructures

Progress Navolchi project

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Outline

- People
- **Materials**
- Processing
- Properties
- Devices
 - Absorbance of functionalized waveguides
- Planning of future work



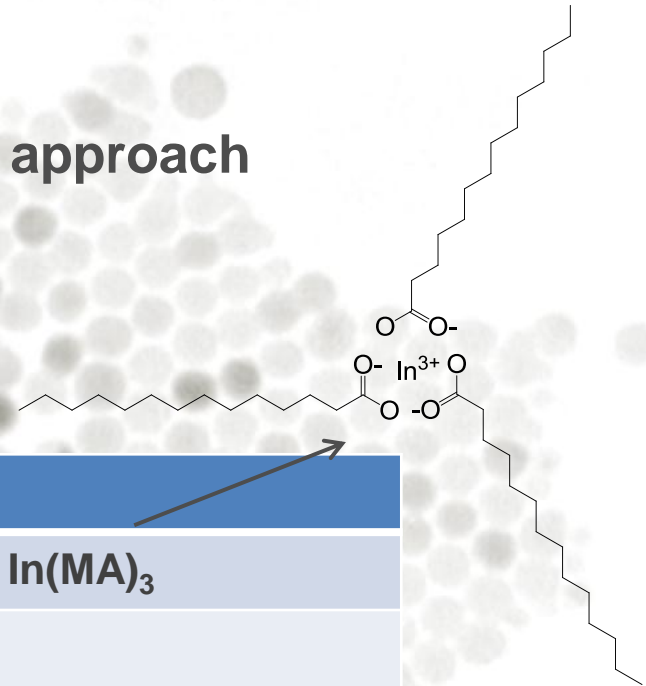
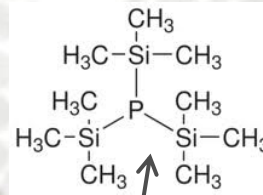
Materials

- **InP/CdS**
 - **Why?**
 - Type 2 heterostructure with emission wavelength > 1000 nm
 - **Challenges**
 - CdS shell growth seems difficult according to literature
 - Based on bulk band alignment, 1500 nm is within reach, yet no experimental evidence in literature so far
 - **Current activities**
 - Establish state-of-the-art InP synthesis @ Ugent
 - Push core synthesis to larger diameters
 - Develop reliable shell growth procedure



Materials

- InP/CdS – baseline synthesis
- Variation on published hot injection approach



Synthesis conditions	
Precursors	P(TMS) ₃ and In(MA) ₃
In:P:Octylamine:Myristic Acid	2:1:11:x
Injection Temp.	188 °C
Growth Temp.	178 °C
Reaction time	30 min

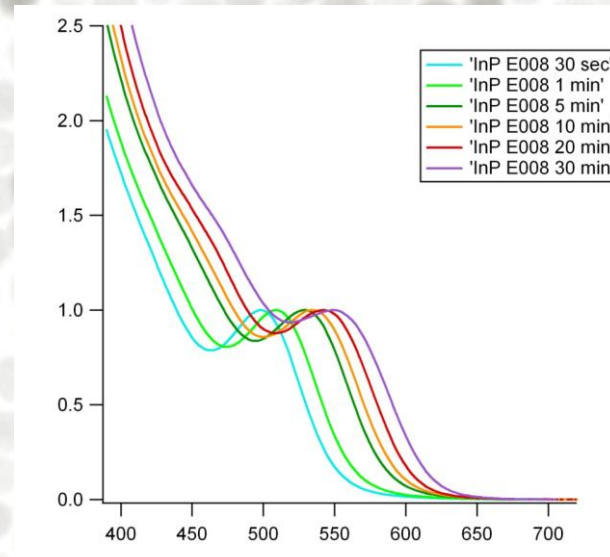
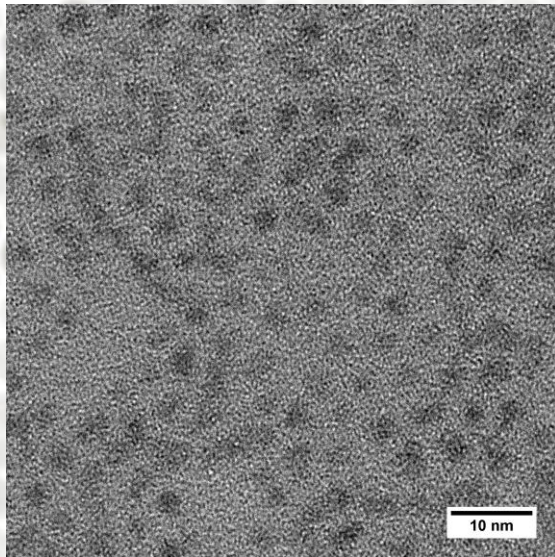
R. Xie, D. Battaglia and X. Peng; J. Am. Chem. Soc. 2007; 129; 15432-15433



Materials

- InP/CdS – baseline synthesis
- Typical result:

In : P: octylamine : MA = 0.4 : 0.2 : 2.2 : 1.70



R. Xie, D. Battaglia and X. Peng; J. Am. Chem. Soc. 2007; 129; 15432-15433



Physics and Chemistry of Nanostructures Group

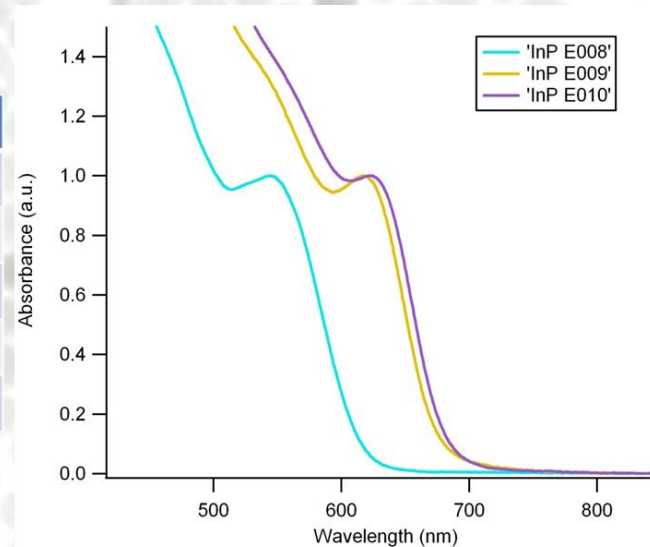
Represented by



Materials

- InP/CdS – baseline synthesis
- Size tuning *via* myristic acid concentration:

Sample	In:MA ratio	Abs. max (nm)
E003	0.4:1.60	485
E007	0.4:1.65	513
E008	0.4:1.70	549
E009	0.4:1.75	615
E010	0.4:1.90	622



Required starting point to push InP/CdS core/shell QDs towards 1300 and 1500 nm

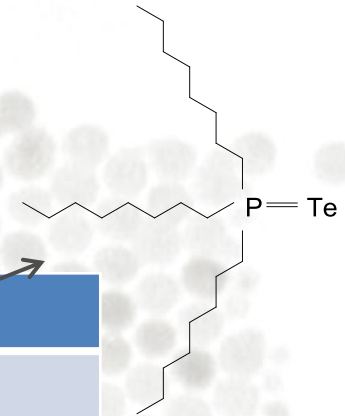
R. Xie, D. Battaglia and X. Peng; J. Am. Chem. Soc. 2007; 129; 15432-15433



Materials

- HgTe – baseline synthetis (under development)
- Variation on published hot injection approach

Synthesis conditions	
Precursors	HgCl ₂ and TOP-Te
Hg:Te	1:1:11:x
Injection Temp.	60 °C
Growth Temp.	60 °C
Reaction time	15 min

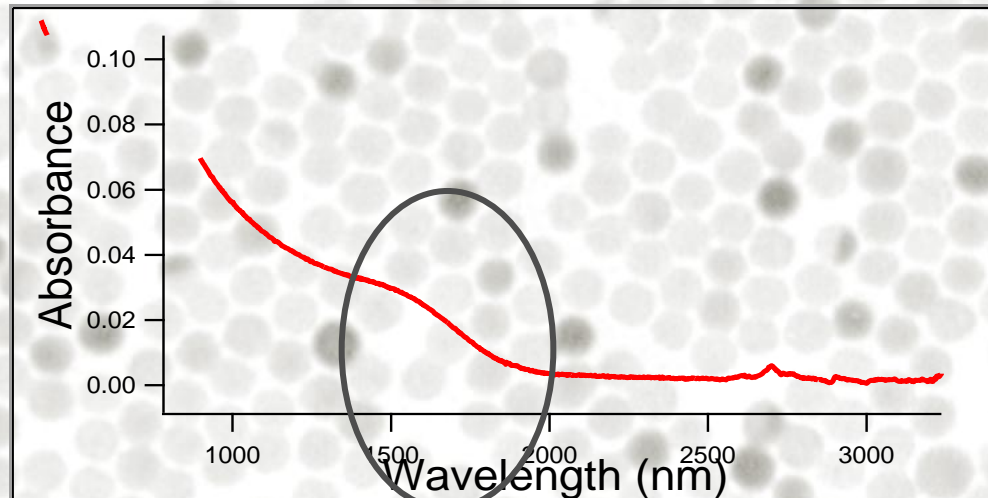


Keuleyan et al., J. Am. Chem. Soc. 2011; 133; 16422-16424



Materials

- HgTe – baseline synthetic
- Initial result:



Band gap in 1500-2000 nm range
=
good starting point to cover wavelengths in 1300-1600 nm range

R. Xie, D. Battaglia and X. Peng; J. Am. Chem. Soc. 2007; 129; 15432-15433



Future work

- **InP**
 - Further push core synthesis to larger sizes
 - Development of CdS shell growth procedure
 - Optical characterization
- **HgTe**
 - Enhance size dispersion
 - Optimize size control in the required wavelength range
 - Optical characterization

